

SURFACE MOUNT SILICON ZENER DIODES
VOLTAGE 2.4 - 39 Volts

POWER 200 mWatts

PACKAGE SOT-323

FEATURES

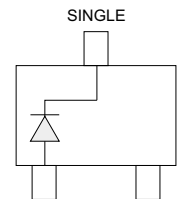
- Planar Die construction
- 200mW Power Dissipation
- Zener Voltages from 2.4V - 39V
- Ideally Suited for Automated Assembly Processes

MECHANICAL DATA

Case: SOT-323, Plastic

Terminals: Solderable per MIL-STD-202, Method 208

Approx. Weight: 0.008 gram


MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Parameter	Symbol	Value	Units
Power Dissipation (Notes A) at 25°C	P _D	200	mW
Peak Forward Surge Current, 8.3ms single half sine-wave superimposed on rated load (JEDEC method) (Notes B)	I _{FSM}	2.0	Amps
Operating Junction and Storage Temperature Range	T _J	-55 to +150	°C

NOTES:

 A. Mounted on 5.0mm²(.013mm thick) land areas.

B. Measured on 8.3ms, single half sine-wave or equivalent square wave, duty cycle = 4 pulses per minute maximum.



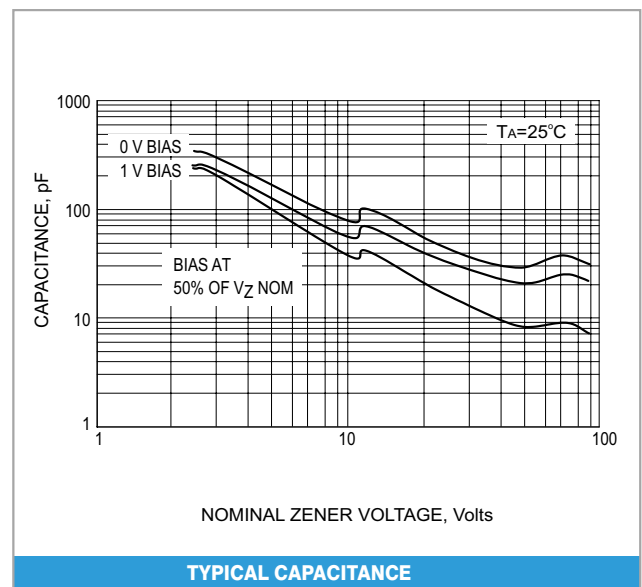
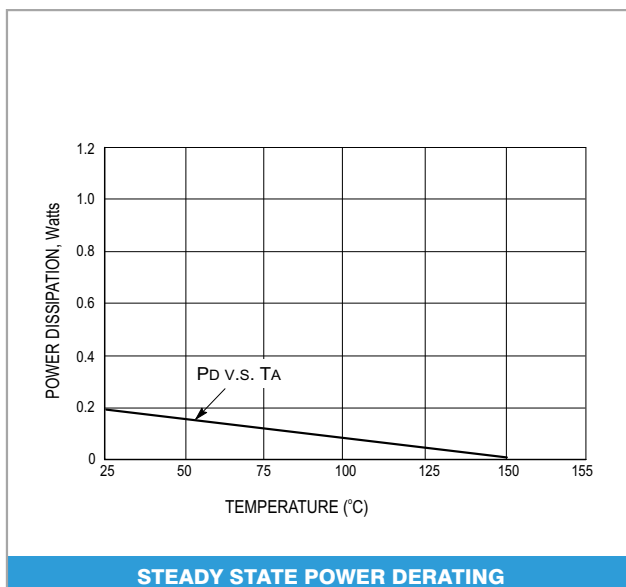
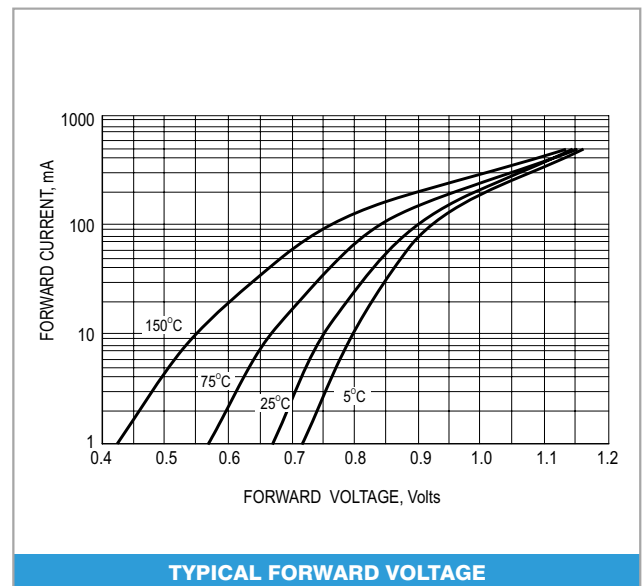
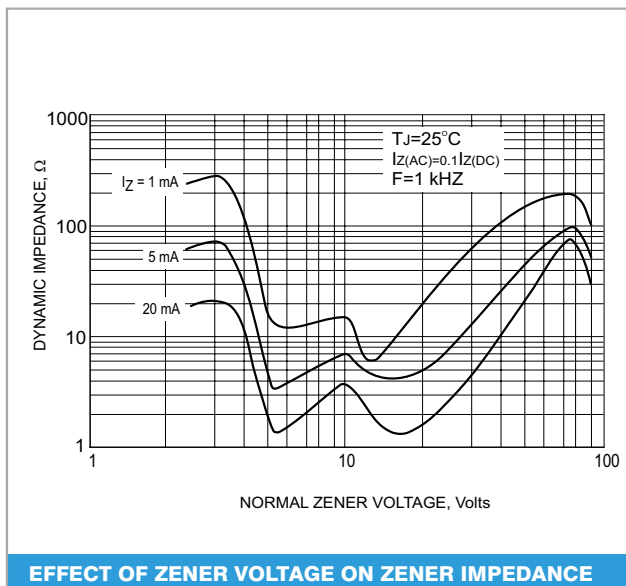
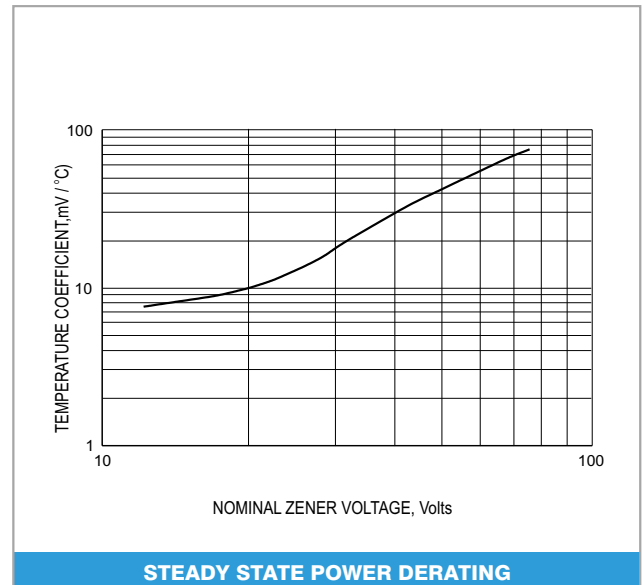
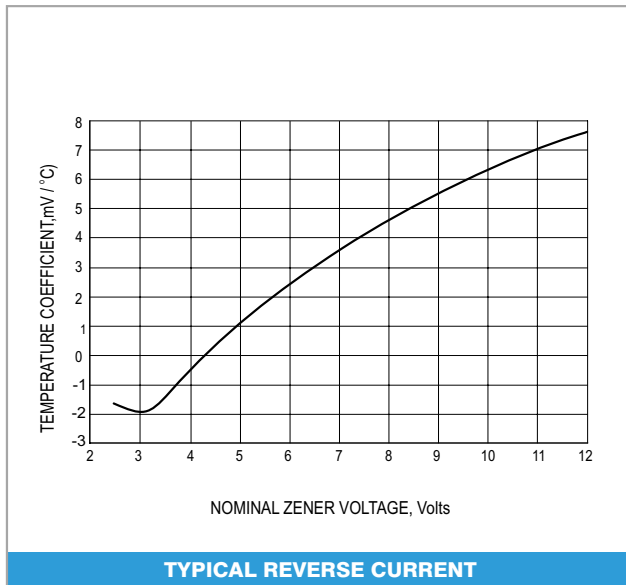
MMBZ5221BW thru MMBZ5259BW

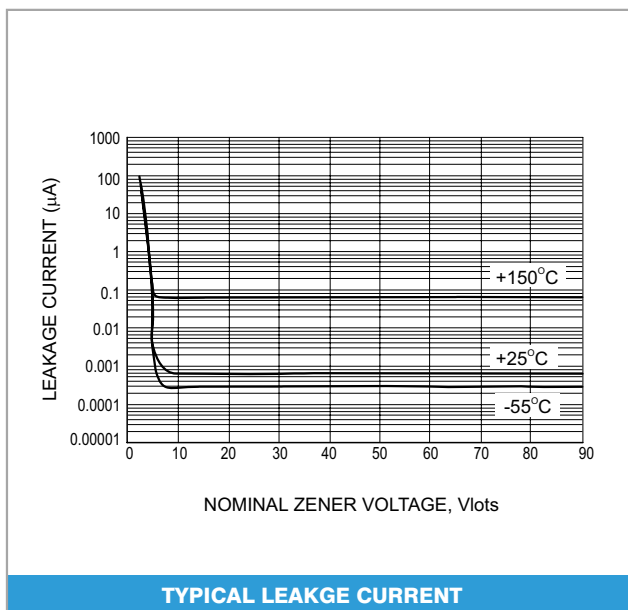
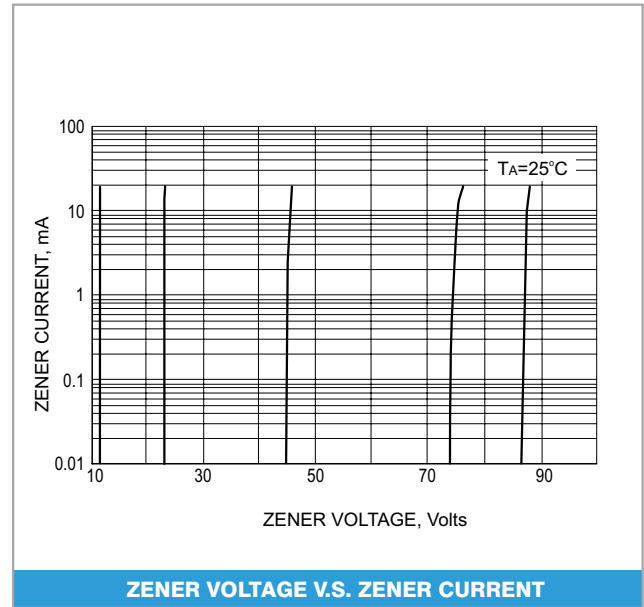
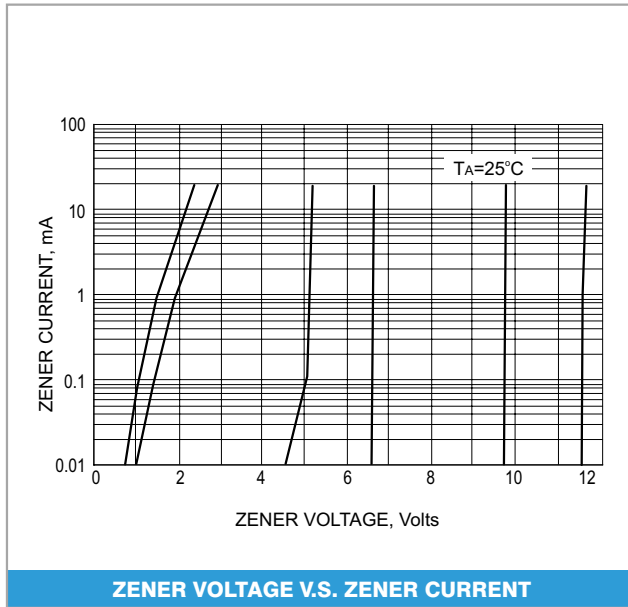
ELECTRICAL CHARACTERISTICS (T_A=25°C unless otherwise noted) V_F=1.2V max, I_F=100mA for all types.

Part Number	Nominal Zener Voltage			Max. Zener Impedance				Max Reverse Leakage Current		Package
	V _Z @ I _{ZT}			Z _{ZT} @ I _{ZT}		Z _{ZK} @ I _{ZK}		I _R @ V _R		
	Nom. V	Min. V	Max. V	Ω	mA	Ω	mA	μA	V	
200 mWatts Zener Diodes										
MMBZ5221BW	2.4	2.28	2.52	30	20	1200	0.25	100	1	SOT-323
MMBZ5222BW	2.5	2.38	2.63	30	20	1250	0.25	100	1	SOT-323
MMBZ5223BW	2.7	2.57	2.84	30	20	1300	0.25	75	1	SOT-323
MMBZ5225BW	3	2.85	3.15	30	20	1600	0.25	50	1	SOT-323
MMBZ5226BW	3.3	3.14	3.47	28	20	1600	0.25	25	1	SOT-323
MMBZ5227BW	3.6	3.42	3.78	24	20	1700	0.25	15	1	SOT-323
MMBZ5228BW	3.9	3.71	4.1	23	20	1900	0.25	10	1	SOT-323
MMBZ5229BW	4.3	4.09	4.52	22	20	2000	0.25	5	1	SOT-323
MMBZ5230BW	4.7	4.47	4.94	19	20	1900	0.25	5	2	SOT-323
MMBZ5231BW	5.1	4.85	5.36	17	20	1600	0.25	5	2	SOT-323
MMBZ5232BW	5.6	5.32	5.88	11	20	1600	0.25	5	3	SOT-323
MMBZ5234BW	6.2	5.89	6.51	7	20	1000	0.25	5	4	SOT-323
MMBZ5235BW	6.8	6.46	7.14	5	20	750	0.25	3	5	SOT-323
MMBZ5236BW	7.5	7.13	7.88	6	20	500	0.25	3	6	SOT-323
MMBZ5237BW	8.2	7.79	8.61	8	20	500	0.25	3	6	SOT-323
MMBZ5239BW	9.1	8.65	9.56	10	20	600	0.25	3	6.5	SOT-323
MMBZ5240BW	10	9.5	10.5	17	20	600	0.25	3	8	SOT-323
MMBZ5241BW	11	10.45	11.55	22	20	600	0.25	3	8.4	SOT-323
MMBZ5242BW	12	11.4	12.6	30	20	600	0.25	2	9.1	SOT-323
MMBZ5243BW	13	12.35	13.65	13	9.5	600	0.25	1	9.9	SOT-323
MMBZ5245BW	15	14.25	15.75	16	8.5	600	0.25	0.5	11	SOT-323
MMBZ5246BW	16	15.2	16.8	17	7.8	600	0.25	0.1	12	SOT-323
MMBZ5248BW	18	17.1	18.9	21	7	600	0.25	0.1	14	SOT-323
MMBZ5250BW	20	19	21	25	6.2	600	0.25	0.1	15	SOT-323
MMBZ5251BW	22	20.9	23.1	29	5.6	600	0.25	0.1	17	SOT-323
MMBZ5252BW	24	22.8	25.2	33	5.2	600	0.25	0.1	18	SOT-323
MMBZ5254BW	27	25.65	28.35	41	5	600	0.25	0.1	21	SOT-323
MMBZ5255BW	28	26.6	29.4	44	4.5	600	0.25	0.1	21	SOT-323
MMBZ5256BW	30	28.5	31.5	49	4.2	600	0.25	0.1	23	SOT-323
MMBZ5257BW	33	31.35	34.65	58	3.8	700	0.25	0.1	25	SOT-323
MMBZ5258BW	36	34.2	37.8	70	3.4	700	0.25	0.1	27	SOT-323
MMBZ5259BW	39	37.05	40.95	80	3.2	800	0.25	0.1	30	SOT-323

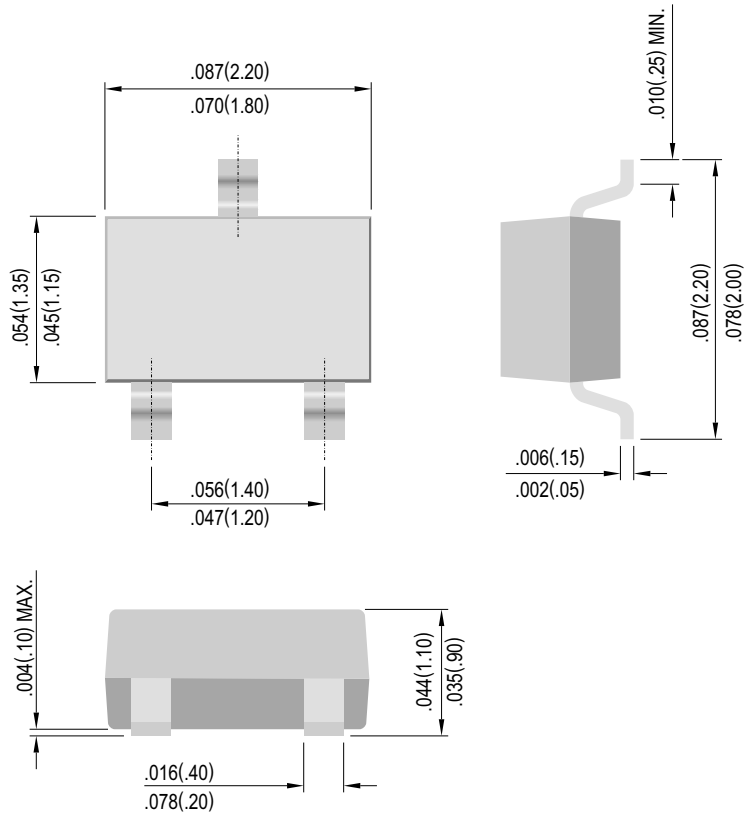
NOTE:

- Tolerance and Type Number Designation. The type numbers listed have a standard tolerance on the nominal zener voltage of ±5%.
- Specials Available Include:
 - Nominal zener voltages between the voltages shown and tighter voltage tolerances.
 - Matched sets.
- Zener Voltage (V_Z) Measurement. Guarantees the zener voltage when measured at 90 seconds while maintaining the lead temperature (T_L) at 30°C, from the diode body.
- Zener Impedance (Z_Z) Derivation. The zener impedance is derived from the 60 cycle ac voltage, which results when an AC current having an rms value equal to 10% of the dc zener current (I_{ZT} or I_{ZK}) is superimposed on I_{ZT} or I_{ZK}.
- Surge Current (I_R) Non-Repetitive. The rating listed in the electrical characteristics table is maximum peak, non-repetitive, reverse surge current of 1/2 square wave or equivalent sine wave pulse of 1/120 second duration superimposed on the test current, I_{ZT}, per JEDEC registration; however, actual device capability is as described in Figure 5.





SOT-323



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